

# NPN Triple Diffused Planar Silicon Transistor

## **FJL6920**

#### **Features**

- High Collector–Base Breakdown Voltage: BV<sub>CBO</sub> = 1700 V
- Low Saturation Voltage: V<sub>CE</sub>(sat) = 3 V (Max.)
- For Color Monitor
- These Devices are Pb-Free, Halide Free and are RoHS Compliant

#### **Applications**

• High Voltage Color Display Horizontal Deflection Output

#### ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = 25°C unless otherwise noted)

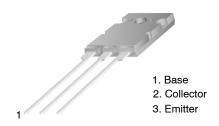
Parameter	Symbol	Rating	Units
Collector-Base Voltage	$V_{CBO}$	1700	V
Collector-Emitter Voltage	$V_{CEO}$	800	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Collector Current (DC)	I <sub>C</sub>	20	Α
Collector Current (Pulse) *	I <sub>CP</sub>	30	Α
Collector Dissipation	P <sub>C</sub>	200	W
Junction Temperature	ire T <sub>J</sub> 150		°C
Storage Temperature	T <sub>J</sub> , T <sub>STG</sub>	<b>−55 ~ 150</b>	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### **THERMAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

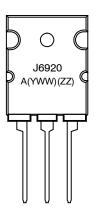
Parameter	Symbol	Max.	Units
Thermal Resistance, Junction to Case	$R_{ heta JC}$	0.625	°C/W

1



TO-264-3LD CASE 340CA

#### MARKING DIAGRAM



J6920 = Specific Device Code

A = Assembly Site

Y = Year of Production, Last Number

WW = Work Week Number

ZZ = Assembly Lot Number, Last Two Numbers

#### **ORDERING INFORMATION**

Device	Package	Shipping		
FJL6920TU	TO-264-3LD	375 Units / Tube		

<sup>\*</sup>Pulse Test: PW = 300 μs, Duty Cycle = 2% Pulsed

#### FJL6920

### **ELECTRICAL CHARACTERISTICS** (Note 1) ( $T_C = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
I <sub>CES</sub>	Collector Cut-Off Current	V <sub>CB</sub> = 1400 V, R <sub>BE</sub> = 0			1	mA
I <sub>CBO</sub>	Collector Cut-Off Current	V <sub>CB</sub> = 800 V, I <sub>E</sub> = 0			10	μΑ
I <sub>EBO</sub>	Emitter Cut-Off Current	V <sub>EB</sub> = 4 V, I <sub>C</sub> = 0			1	mA
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 500 \mu A, I_E = 0$	1700			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 5 mA, I <sub>B</sub> = 0	800			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 500 \mu A, I_C = 0$	6			V
h <sub>FE1</sub>	DC Current Gain	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A	8			
h <sub>FE2</sub>	DC Current Gain	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 11 A	5.5		8.5	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 11 A, I <sub>B</sub> = 2.75 A			3	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = 11 A, I <sub>B</sub> = 2.75 A			1.5	V
t <sub>STG</sub>	Storage Time (Note 1)	$V_{CC}$ = 200 V, $I_{C}$ = 10 A, $R_{L}$ = 20 $\Omega$ , $I_{B1}$ = 2.0 A, $I_{B2}$ = -4.0 A			3	μs
t <sub>F</sub>	Fall Time (Note 1)	$V_{CC}$ = 200 V, $I_{C}$ = 10 A, $R_{L}$ = 20 $\Omega$ , $I_{B1}$ = 2.0 A, $I_{B2}$ = -4.0 A		0.15	0.2	μs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: PW = 20 µs, Duty Cycle = 1% Pulsed

#### **TYPICAL CHARACTERISTICS**

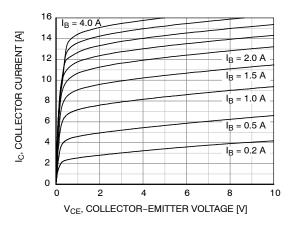


Figure 1. Static Characteristic

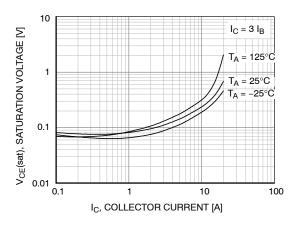


Figure 3. Collector-Emitter Saturation Voltage

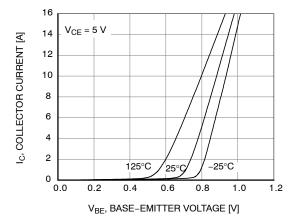


Figure 5. Base-Emitter On Voltage

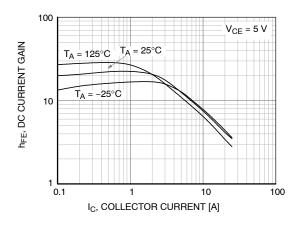


Figure 2. DC Current Gain

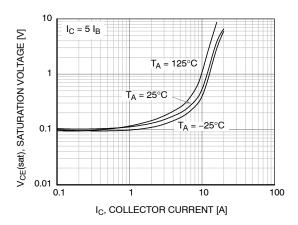


Figure 4. Collector-Emitter Saturation Voltage

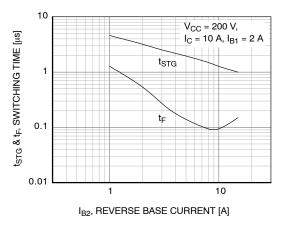


Figure 6. Resistive Load Switching Time

#### TYPICAL CHARACTERISTICS (Continued)

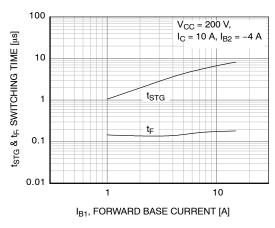


Figure 7. Resistive Load Switching Time

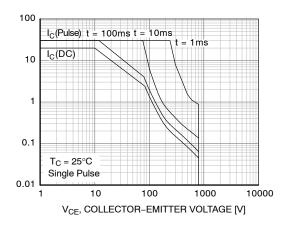


Figure 9. Forward Bias Safe Operating Area

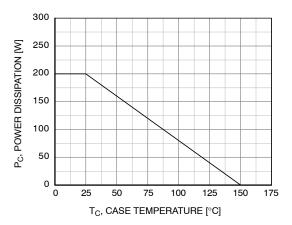


Figure 11. Power Derating

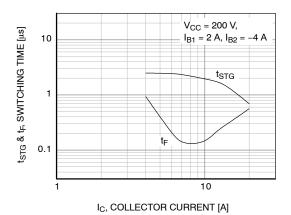


Figure 8. Resistive Load Switching Time

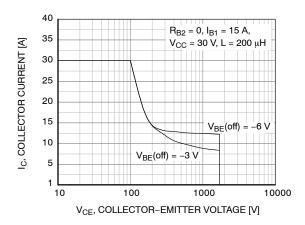
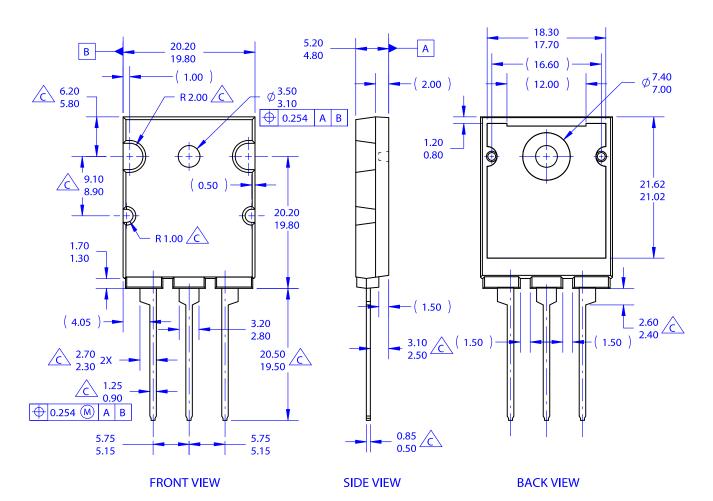


Figure 10. Reverse Bias Safe Operating Area



TO-264-3LD CASE 340CA ISSUE O

**DATE 31 OCT 2016** 



# 3.70 3.30 4.80 BOTTOM VIEW

#### NOTES:

- A. PACKAGE REFERENCE: JEDEC TO264 VARIATION AA.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- OUT OF JEDEC STANDARD VALUE.

  D. DIMENSION AND TOLERANCE AS PER ASME
  Y14.5-1994.
  - E. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.

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